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PATENT NUMBER and  
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10089479	FILING DATE 03/28/2002	CLASS 438	SUBCLASS 488	CAU 2812	EXAMINER D. NHU
<b>**APPLICANTS:</b> Kim Bong-Cheol;					
<b>**CONTINUING DATA VERIFIED:</b> THIS APPLICATION IS A 371 OF PCT/KR00/00935 08/21/2000					
<b>** FOREIGN APPLICATIONS VERIFIED:</b> REPUBLIC OF KOREA 1999-41892 09/30/1999					
PG-PUB		DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>	
Foreign priority claimed		<input type="checkbox"/> yes <input type="checkbox"/> no		ATTORNEY DOCKET NO	
35 USC 119 conditions met		<input type="checkbox"/> yes <input type="checkbox"/> no		A35109 PCT USA	
Verified and Acknowledged Examiners's initials					
<b>TITLE :</b> Apparatus and method for forming single crystalline nitride substrate using hydride vapor phase epitaxy and laser beam					

U.S. DEPT. OF COMM. (PAT. & TM.) PTO-436 (Rev. 12-94)

<b>NOTICE OF ALLOWANCE MAILED</b>		<b>CLAIMS ALLOWED</b>	
		Total Claims	Print Claim for O.G.
<b>ISSUE FEE</b>		<b>DRAWING</b>	
Amount Due	Date Paid	Sheets Drwg.	Figs. Drwg. Print Fig.
<input type="checkbox"/> <b>TERMINAL DISCLAIMER</b>		<b>Application Examiner</b>	
		<b>PREPARED FOR ISSUE</b>	
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